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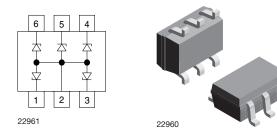
RoHS

HALOGEN

FREE GREEN

(5-2008)

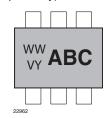
## Five-Line ESD Protection Diode Array in SOT-363



## **FEATURES**

- Compact SOT-363 package
- 5-line unidirectional ESD-protection
- Working range 5V to 26 V
- ESD immunity acc. IEC 61000-4-2 ±20kV to ± 30 kV contact discharge ±20kV to ± 30 kV air discharge
- AEC-Q101 qualified available
- Lead plating: Sn (e3)
  - soldering can be checked by standard vision inspection
  - (AOI = automated optical inspection)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **MARKING** (example only)



Bar = cathode marking

X = date code

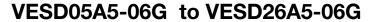
Y = type code (see table below)

#### **DESIGN SUPPORT TOOLS AVAILABLE**



ORDERING INFORMATION									
	ENVIRONMENTAL AND QUALITY CODE								
PART NUMBER (EXAMPLE)	AEC-Q101 RoHS COMPLIANT + LEAD (Pb)-FREE TERMINATIONS TIN PLATED		TIN PLATED	3K PER 7" REEL (8 mm TAPE)	ORDERING CODE (EXAMPLE)				
		GREEN		MOQ = 15K/BOX					
VESD05A5-06G	-	G	3	-08	VESD05A5-06G-G3-08				
VESD05A5-06G	Н	G	3	-08	VESD05A5-06GHG3-08				

PACKAGE DATA										
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS				
VESD05A5-06G		D05								
VESD12A5-06G	SOT-363	D12	UL 94 V-0	MSL level 1	Peak temperature					
VESD16A5-06G	501-303	D16	7.22 mg	OL 94 V-0	(according J-STD-020)	max. 260°C				
VESD26A5-06G		D26								





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ABSOLUTE MAXIMUM RATINGS VESD05A5-06G									
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT					
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I <sub>PPM</sub>	8.7	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot	P <sub>PP</sub>	100	W					
FOD :	Contact discharge acc. IEC 61000-4-2; 10 pulses		30	kV					
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	30	kV					
Operating temperature	Junction temperature	T <sub>J</sub>	-55 to +150	°C					
Storage temperature		T <sub>stg</sub>	-55 to +150	°C					

ABSOLUTE MAXIMUM RATINGS VESD12A5-06G									
PARAMETER	TEST CONDITIONS	SYMBOL	SYMBOL VALUE						
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	4.4	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P <sub>PP</sub>	100	W					
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	W	30	kV					
ESD IIIIIIIIIIII	Air discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	30	kV					
Operating temperature	Junction temperature	TJ	-55 to +150	°C					
Storage temperature		T <sub>stg</sub>	-55 to +150	°C					

ABSOLUTE MAXIMUM RATINGS VESD16A5-06G									
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT					
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	3.6	А					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot	P <sub>PP</sub>	100	W					
CCD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	30	kV					
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	3.6 100	kV					
Operating temperature	Junction temperature	T <sub>J</sub>	-55 to +150	°C					
Storage temperature		T <sub>stg</sub>	-55 to +150	°C					

ABSOLUTE MAXIMUM RATINGS VESD26A5-06G									
PARAMETER	TEST CONDITIONS	ST CONDITIONS SYMBOL VALUE		UNIT					
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	2.1	Α					
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P <sub>PP</sub>	100	W					
ECD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	W	20	kV					
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	lses V <sub>ESD</sub>	20	kV					
Operating temperature	Junction temperature	$T_J$	-55 to +150	°C					
Storage temperature		T <sub>stg</sub>	-55 to +150	°C					



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<b>ELECTRICAL CHARACTERISTICS</b> VESD05A5-06G (T <sub>amb</sub> = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT				
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines				
Reverse stand off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	5	V				
Reverse voltage	at I <sub>R</sub> = 1 μA	V <sub>R</sub>	5	-	-	V				
Reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	0.01	0.1	μΑ				
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6.85	7.26	7.65	V				
Reverse clamping voltage	at $I_{PP} = I_{PPM} = 8.7 \text{ A}$ , $t_p = 8/20 \mu\text{s}$	V <sub>C</sub>	-	10.3	11.5	V				
Forward clamping voltage	at I <sub>PP</sub> = 1 A, t <sub>p</sub> = 300 μs	V <sub>F</sub>	0.9	1.1	1.2	V				
Forward clamping voltage	at $I_{PP} = I_{PPM} = 8.7 \text{ A}$ , $t_p = 8/20 \mu\text{s}$	V <sub>F</sub>	-	2.2	2.74	V				
Dynamic resistance	t <sub>p</sub> = 100 ns (TLP; pin 2-1)	r <sub>dyn</sub>	-	0.2	-	Ω				
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	53	67	81	pF				

ELECTRICAL CHARACTERISTICS VESD12A5-06G (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines			
Reverse stand off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	12	V			
Reverse voltage	at I <sub>R</sub> = 0.1 μA	$V_R$	12	-	-	V			
Reverse current	at V <sub>R</sub> = 12 V	I <sub>R</sub>	-	0.01	0.1	μA			
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	13.9	14.7	15.5	V			
Reverse clamping voltage	at $I_{PP} = I_{PPM} = 4.4 \text{ A}$ , $t_p = 8/20 \mu\text{s}$	V <sub>C</sub>	-	20.5	22.7	V			
Converd elemning veltage	at $I_{PP} = 1 \text{ A}$ , $t_p = 300 \mu\text{s}$	$V_{F}$	0.9	1.1	1.2	V			
Forward clamping voltage	at $I_{PP} = I_{PPM} = 4.4 \text{ A}, t_p = 8/20 \mu \text{s}$	V <sub>F</sub>	-	1.6	1.88	V			
Dynamic resistance	t <sub>p</sub> = 100 ns (TLP); pin 2-1	r <sub>dyn</sub>	-	0.4	-	Ω			
Capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	26	33	40	pF			

<b>ELECTRICAL CHARACTERISTICS</b> VESD16A5-06G (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines			
Reverse stand off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	16	V			
Reverse voltage	at I <sub>R</sub> = 0.1 μA	$V_R$	16	-	-	V			
Reverse current	at V <sub>R</sub> = 16 V	I <sub>R</sub>	-	0.01	0.1	μΑ			
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	17	17.9	18.8	V			
Reverse clamping voltage	at $I_{PP} = I_{PPM} = 3.6 \text{ A}, t_p = 8/20 \mu\text{s}$	V <sub>C</sub>	-	25.3	28	V			
Commend alamanian maltana	at I <sub>PP</sub> = 1 A, t <sub>p</sub> = 300 μs	V <sub>F</sub>	0.9	1.1	1.2	V			
Forward clamping voltage	at I <sub>PP</sub> = I <sub>PPM</sub> = 3.6 A, t <sub>p</sub> = 8/20 μs	$V_{F}$	-	1.5	1.72	V			
Dynamic resistance	t <sub>p</sub> = 100 ns (TLP); pin 2-1	r <sub>dyn</sub>	-	0.53	-	Ω			
Capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	$C_D$	21	27	33	pF			



# **VESD05A5-06G to VESD26A5-06G**

ELECTRICAL CHARACTERISTICS VESD26A5-06G (T <sub>amb</sub> = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT				
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines				
Reverse stand off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	26	V				
Reverse voltage	at I <sub>R</sub> = 0.1 μA	$V_R$	26	-	-	V				
Reverse current	at V <sub>R</sub> = 26 V	I <sub>R</sub>	-	< 0.01	0.1	μA				
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	27.6	29.1	30.6	V				
Reverse clamping voltage	at I <sub>PP</sub> = I <sub>PPM</sub> = 2.1 A, t <sub>p</sub> = 8/20 μs	V <sub>C</sub>	-	43	48	V				
Converd elemening veltage	at I <sub>PP</sub> = 1 A, t <sub>p</sub> = 300 μs	$V_{F}$	0.9	1.1	1.2	V				
Forward clamping voltage	at I <sub>PP</sub> = I <sub>PPM</sub> = 2.1 A, t <sub>p</sub> = 8/20 μs	$V_{F}$	-	1.3	1.42	V				
Dynamic resistance	t <sub>p</sub> = 100 ns (TLP); pin 2-1	r <sub>dyn</sub>	-	1.9	-	Ω				
Capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	14	17.5	21	pF				

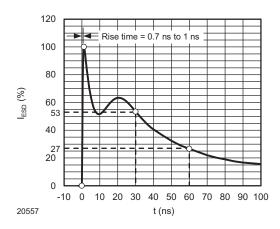


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega$  / 150 pF)

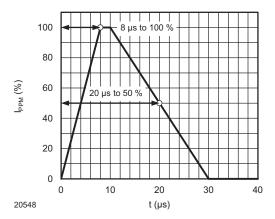


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

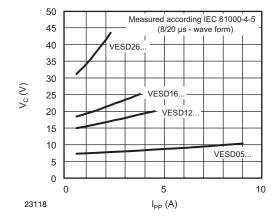


Fig. 3 - Typical Peak Clamping Voltage vs. Peak Pulse Current

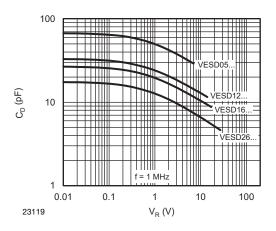


Fig. 4 - Typical Capacitance vs. Reverse Voltage

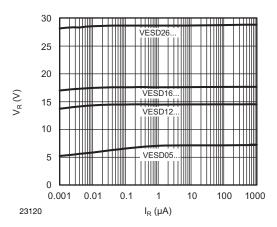


Fig. 5 - Typical Reverse Voltage vs. Reverse Current

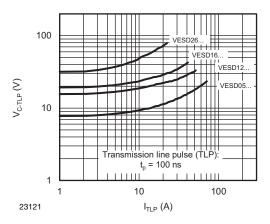
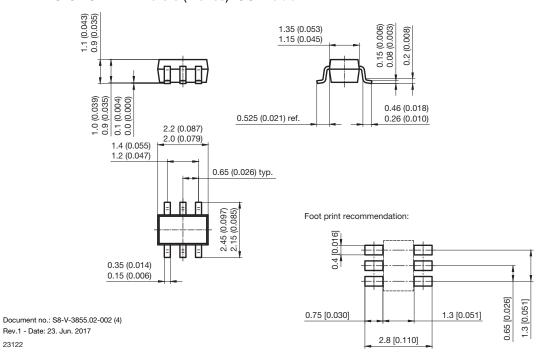


Fig. 6 - Typical Clamping Voltage vs. Peak Pulse Current

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#### PACKAGE DIMENSIONS in millimeters (Inches): SOT-363



#### **CARRIER TAPE SOT-363**

23122

# A-A section Р1 $0.2 \pm 0.05$ B В

**B-B** section



Cummulative tolerances of 10 sprocket holes is  $\pm$  0.2 mm

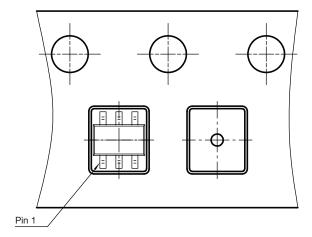
Dimensions in millimeters										
Packaging type	Α	В	С	d	Е	F	P0	Р	P1	W
SOT-363	2.25	2.55	1.20	Ø 1.5	1.75	3.50	4.00	4.00	2.00	8.00
(Tolerance)	± 0.1	± 0.1	± 0.1	+0.1/-0	± 0.1	± 0.1	± 0.05	± 0.1	± 0.05	+0.3/-0.1

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#### **ORIENTATION IN CARRIER TAPE SOT-363**



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